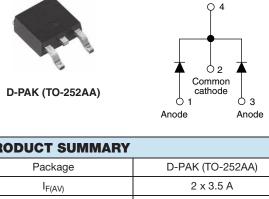
Vishay Semiconductors

Schottky Rectifier, 2 x 3.5 A



Base common cathode

PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I _{F(AV)}	2 x 3.5 A						
V _R	60 V						
V _F at I _F	See Electrical table						
I _{RM}	30 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Common cathode						
E _{AS}	6 mJ						

FEATURES

- Popular D-PAK outline
- Center tap configuration
- · Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

DESCRIPTION

The VS-6CWQ06FNPbF surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	7	А						
V _{RRM}		60	V						
I _{FSM}	t _p = 5 μs sine	490	А						
V _F	3 Apk, T _J = 25 °C (per leg)	0.61	V						
TJ	Range	- 40 to 150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-6CWQ06FNPbF	UNITS						
Maximum DC reverse voltage	V _R	60	V						
Maximum working peak reverse voltage	V _{RWM}	00	V						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS					
Maximum average per leg		50 % duty cycle at $T_{a} = 133$ °C	% duty cycle at T _C = 133 °C, rectangular waveform						
See fig. 5 per device	I _{F(AV)}	30% duty cycle at $1^\circ_{\rm C} = 135\%$	7	А					
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	490					
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	70					
Non-repetitive avalanche energy per leg	petitive avalanche energy per leg E_{AS} $T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 12 \text{ mH}$		6	mJ					
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero Frequency limited by T_J maximum	•	1	А				



RoHS COMPLIANT



For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST C	CONDITIONS	VALUES	UNITS			
		3 A	T.I = 25 °C	0.61	V			
Maximum forward	V (1)	6 A	1j=25 C	0.76				
voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	3 A	T 105 %O	0.53				
		6 A	— T _J = 125 °C	0.65	1			
Maximum reverse	. (1)	T _J = 25 °C		2	0			
leakage current per leg See fig. 2	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	30	mA			
Threshold voltage	V _{F(TO)}	T T		0.38	V			
Forward slope resistance	r _t	$T_J = T_J$ maximum		34.31	mΩ			
Typical junction capacitance per leg	C _T	$V_{\rm R}$ = 5 $V_{\rm DC}$, (test signal i	145	pF				
Typical series inductance per leg	L _S	Measured lead to lead	5.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T_{J} ⁽¹⁾ , T_{Stg}		- 40 to 150	°C				
Maximum thermal resistance,	per leg	D	DC operation	4.70	°C/W				
junction to case	per device	R _{thJC}	See fig. 4	2.35	0/11				
Approximate weight				0.3	g				
				0.01	OZ.				
Marking device			Case style D-PAK (similar to TO-252AA)	6CWQ06FN					

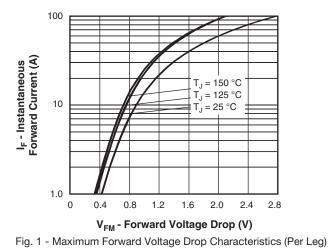
Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



Schottky Rectifier, 2 x 3.5 A

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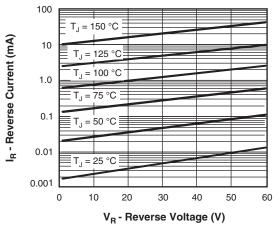


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

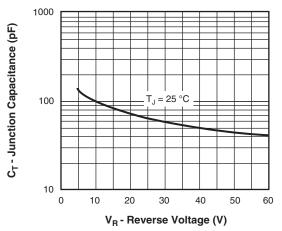


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

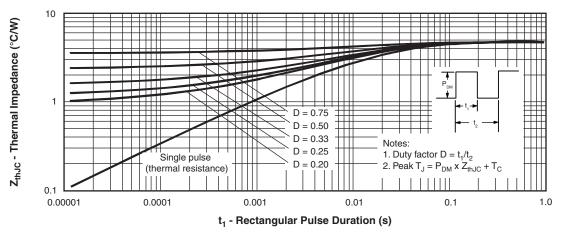
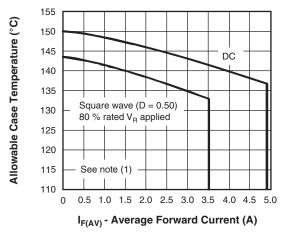


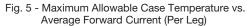
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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Schottky Rectifier, 2 x 3.5 A







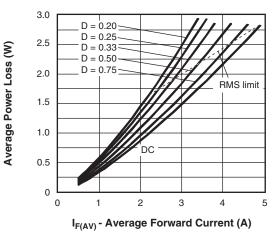


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

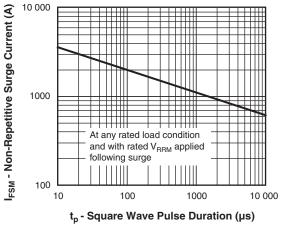


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

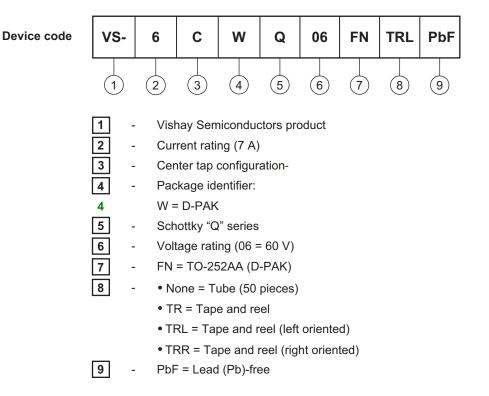
⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;



Schottky Rectifier, 2 x 3.5 A

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ORDERING INFORMATION TABLE



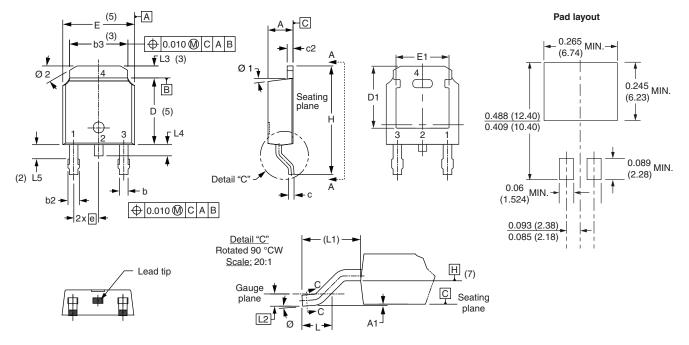
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95016					
Part marking information	www.vishay.com/doc?95059					
Packaging information	www.vishay.com/doc?95033					





D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	INCHES		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NUTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090) BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5]	Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

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